Analog Power AM3456N

## N-Channel 30V (D-S) MOSFET

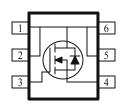
These miniature surface mount MOSFETs utilize High Cell Density process. Low  $r_{DS(on)}$  assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are power switch, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low r <sub>DS(on)</sub> Provides Higher Efficiency and
	Extends Battery Life

- Low Gate Charge
- Fast Switch
- Miniature TSOP-6 Surface Mount Package Saves Board Space

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)}(\Omega)$	<b>I</b> <sub>D</sub> (A)	
30	$0.044 @ V_{GS} = 10 V$	5.1	
30	$0.064 @ V_{GS} = 4.5V$	4.5	





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Maximum	Units	
Drain-Source Voltage			30	V	
Gate-Source Voltage			±20	V	
C t D · C ta	$T_A=25^{\circ}C$	. T_	5.5		
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	4.4	A	
Pulsed Drain Current <sup>b</sup>		$I_{DM}$	±20		
Continuous Source Current (Diode Conduction) <sup>a</sup>			1.3	A	
D D: : a	$T_A=25^{\circ}C$	$\mathbf{D}_{-}$	2.0	W	
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	LD	1.3	VV	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
M . I	t <= 5 sec	D	85	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	Steady-State	$R_{THJA}$	62.5		

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## Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)						
Parameter	Symbol Test Conditions		Limits			Unit
rarameter			Min	Тур	Max	UIII
Switch Off Characteristics						
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA
Zero Gate Voltage Drain Current	<sup>1</sup> DSS	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	
Switch On Characteristics						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1.0			V
		$V_{GS} = 10 \text{ V}, I_D = 5.1 \text{ A}$			44	
Drain-Source On-Resistance <sup>A</sup>	$r_{DS(on)}$	$V_{GS} = 10 \text{ V}, I_D = 5.1 \text{ A } T_J = 55^{\circ}\text{C}$			49	mΩ
		$V_{GS} = 4.5 \text{ V}, I_D = 4.5 \text{ A}$			64	
Forward Tranconductance <sup>A</sup>	$g_{\mathrm{fs}}$	$V_{DS} = 10 \text{ V}, I_D = 5.1 \text{ A}$		45		S
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			A
Diode Forward Voltage	$V_{\mathrm{SD}}$	$I_S = 1.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.75		V
Dynamic <sup>b</sup>						
Total Gate Charge	$Q_{g}$	$V_{DS} = 15 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 5.1 \text{ A}$ $R_{I} = 6 \Omega$		4.0		nC
Gate-Source Charge	$Q_{gs}$			1.1		
Gate-Drain Charge	$Q_{gd}$	$R_{\rm L} = 0.22$		1.4		
Turn-On Delay Time	t <sub>d(on)</sub>			6		
Rise Time	$t_{\rm r}$	$V_{DS} = 15 \text{ V},  R_L = 6 \Omega,  I_D = 1 \text{ A},$		10		ne
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}$		18		ns
Fall-Time	$t_{\mathrm{f}}$			5		

## Notes

- a. Pulse test:  $PW \le 300us duty cycle \le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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